

### POWER MANAGEMENT

#### Description

The SC1112 was designed for the latest high speed motherboards. It includes three low dropout regulator controllers. The controllers provide the power for the system AGTL bus Termination Voltage, Chipset, and clock circuitry.

An adjustable controller with a 1.2V reference is available, while two selectable outputs are provided for the VTT (1.25 V or 1.5V, SC1112) or (1.2V or 1.5V, SC1112A) and the AGP (1.5V or 3.3V). The SC1112 low dropout regulators are designed to track the 3.3V power supply as the VTTIN supply is cycled On and Off. A latched short circuit protection is also available for the VTT output.

Other features include an integrated charge pump that provides adequate gate drives for the external MOSFETs, and a capacitive programmable delay for the power good signal.

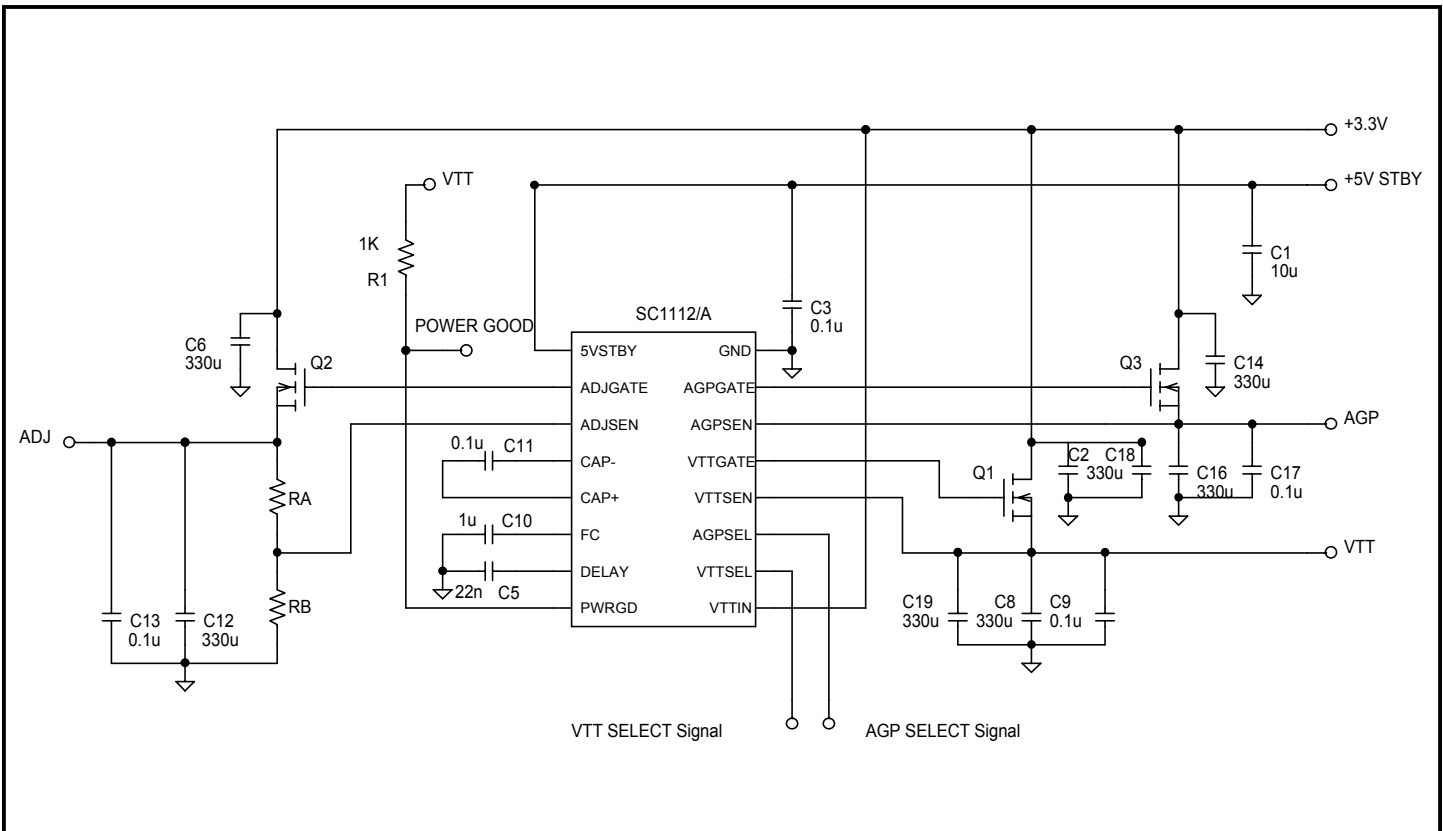
#### Features

- ◆ Triple linear controllers
- ◆ Selectable and adjustable output voltages
- ◆ LDOs track input voltage within 200mV (Function of the MOSFETs used) until regulation
- ◆ Integrated charge pump
- ◆ Programmable power good delay signal
- ◆ Latched over current protection (VTT)
- ◆ Pb-free package available, fully WEEE and RoHS compliant

#### Applications

- ◆ Pentium® III Motherboards
- ◆ Triple power supplies

#### Typical Application Circuit



**POWER MANAGEMENT**
**Absolute Maximum Ratings**

Exceeding the specifications below may result in permanent damage to the device, or device malfunction. Operation outside of the parameters specified in the Electrical Characteristics section is not implied.

| Parameter   | Symbol        | Maximum     | Units |
|---|---------------|-------------|-------|
| 5VSTBY to GND   |               | -0.3 to +7  | V     |
| VTTSEN to GND   |               | -0.3 to 5   | V     |
| AGPSEN to GND   |               | -0.3 to 5   | V     |
| ADJSEN to GND   |               | -0.3 to 5   | V     |
| Operating Temperature Range                             | $T_A$         | 0 to +70    | °C    |
| Junction Temperature Range                              | $T_J$         | 0 to +125   | °C    |
| Storage Temperature Range                               | $T_{STG}$     | -65 to +150 | °C    |
| Lead Temperature (Soldering) 10 Sec.                    | $T_L$         | 300         | °C    |
| Thermal Resistance Junction to Ambient<br>SOIC<br>TSSOP | $\theta_{JA}$ | 130<br>115  | °C/W  |
| Thermal Impedance Junction to Case<br>SOIC<br>TSSOP     | $\theta_{JC}$ | 30<br>38    | °C/W  |
| ESD Rating (Human Body Model)                           | ESD           | 2           | kV    |

**Electrical Characteristics**

Unless specified: 5VSTBY=4.75V to 5.25V; VTTIN=3.3V;  $T_A = 25^\circ\text{C}$

| Parameter  | Symbol           | Conditions                      | Min   | Typ                                   | Max   | Units |
|--|------------------|---------------------------------|-------|---------------------------------------|-------|-------|
| <b>Supply (5VSTBY)</b>                                 |                  |                                 |       |                                       |       |       |
| Supply Voltage   | 5VSTBY           |                                 | 4.75  | 5                                     | 5.25  | V     |
| Supply Current   | $I_{5VSTBY}$     | 5VSTBY = 5V                     | 6     | 8                                     | 12    | mA    |
| <b>VTT Short Circuit Protection</b>                    |                  |                                 |       |                                       |       |       |
| VTT Short Circuit Delay Timer Threshold <sup>(4)</sup> | $SC_{Th}$        |                                 |       | 1.5                                   |       | V     |
| VTT Short Circuit Delay Time <sup>(4)</sup>            | $SC_{td}$        |                                 |       | $(C_{delay} * SC_{Th}) / I_{SC}$      |       | S     |
| VTT Short Circuit Delay Source Current <sup>(4)</sup>  | $I_{SC}$         |                                 | 16    | 22                                    | 28    | µA    |
| VTT Short Circuit Threshold <sup>(4)</sup>             | $VTTSC_{Th}$     |                                 | 650   | 700                                   | 750   | mV    |
| <b>VTT Power Good</b>                                  |                  |                                 |       |                                       |       |       |
| PWRGD Delay Timer Threshold <sup>(5)</sup>             | $PG_{Delay\_TH}$ |                                 | 1.450 | 1.500                                 | 1.550 | V     |
| PWRGD Threshold <sup>(5)</sup>                         | $PG_{TH\_1.2}$   |                                 | 1.060 | 1.085                                 | 1.110 | V     |
| PWRGD Threshold <sup>(5)</sup>                         | $PG_{TH\_1.5}$   |                                 | 1.330 | 1.350                                 | 1.390 | V     |
| PWRGD Delay Time <sup>(5)</sup>                        | $PG_{td\_1.2}$   |                                 |       | $(C_{delay} * PG_{TH\_1.2}) / I_{PG}$ |       | S     |
| PWRGD Delay Time <sup>(5)</sup>                        | $PG_{td\_1.5}$   |                                 |       | $(C_{delay} * PG_{TH\_1.5}) / I_{PG}$ |       | S     |
| PWRGD Source Current <sup>(5)</sup>                    | $I_{PG}$         |                                 | 16    | 22                                    | 28    | µA    |
| <b>Linear Sections</b>                                 |                  |                                 |       |                                       |       |       |
| VTT Input Supply Threshold                             | $VTTIN_{Th}$     |                                 | 1.45  | 1.52                                  | 1.55  | V     |
| Tracking Difference <sup>(1)(3)</sup>                  | $\Delta_{TRACK}$ | $V_{IN} = 3.30V,$<br>$I_O = 0A$ |       | 200                                   |       | mV    |

**POWER MANAGEMENT**
**Electrical Characteristics (Cont.)**

 Unless specified: 5VSTBY=4.75V to 5.25V; VTTIN=3.3V; T<sub>A</sub> = 25°C

| Parameter                      | Symbol                                 | Conditions                                  | Min   | Typ           | Max   | Units |
|--------------------------------|--|---|-------|---------------|-------|-------|
| <b>Linear Sections (Cont.)</b> |  |   |       |               |       |       |
| Output Voltage VTT             | (SC1112A)<br>VTT <sub>1.2</sub>        | I <sub>o</sub> = 0 to 2A, VTTSEL = LOW      | 1.176 | 1.200         | 1.224 | V     |
|                                | (SC1112)<br>VTT <sub>1.25</sub>        | I <sub>o</sub> = 0 to 2A, VTTSEL = LOW      | 1.225 | 1.250         | 1.275 |       |
|                                | VTT <sub>1.5</sub>                     | I <sub>o</sub> = 0 to 2A, VTTSEL = HIGH     | 1.470 | 1.500         | 1.530 | V     |
| Output Voltage AGP             | AGP <sub>1.5</sub>                     | I <sub>o</sub> = 0 to 2A, AGPSEL = LOW      | 1.470 | 1.500         | 1.530 | V     |
|                                | AGP <sub>3.3</sub>                     | I <sub>o</sub> = 0 to 2A, AGPSEL = HIGH     | 3.234 | 3.300         |       | V     |
| Output Voltage ADJ             | ADJ                                    | I <sub>o</sub> = 0 to 2A                    | -2%   | 1.2*(1+RA/RB) | +2%   | V     |
| VTTSEN Bias Current (SC1112)   | I <sub>bias</sub> <sub>VTTSEN</sub>    |   | 90    | 120           | 140   | μA    |
| VTTSEN Bias Current (SC1112A)  | I <sub>bias</sub> <sub>VTTSEN</sub>    |   |       | 1             | 5     | μA    |
| AGPSEN Bias Current            | I <sub>bias</sub> <sub>AGPSEN</sub>    |   | 110   | 150           | 170   | μA    |
| ADJSEN Bias Current            | I <sub>bias</sub> <sub>ADJSEN</sub>    |   |       | 1             | 5     | μA    |
| VTT Gate Current               | I <sub>source</sub> <sub>VTTgate</sub> | 5VSTBY = 4.75V, Vgate = 3.0V                |       | 500           |       | μA    |
|                                | I <sub>sink</sub> <sub>VTTgate</sub>   |   |       | 500           |       | μA    |
| AGP Gate Current               | I <sub>source</sub> <sub>AGPgate</sub> | 5VSTBY = 4.75V, Vgate = 3.0V                |       | 500           |       | μA    |
|                                | I <sub>sink</sub> <sub>AGPgate</sub>   |   |       | 500           |       | μA    |
| ADJ Gate Current               | I <sub>source</sub> <sub>ADJgate</sub> | 5VSTBY = 4.75V, Vgate = 3.0V                |       | 500           |       | μA    |
|                                | I <sub>sink</sub> <sub>ADJgate</sub>   |   |       | 500           |       | μA    |
| Load Regulation                | LOAD <sub>REG</sub>                    | VTTIN = 3.30V, I <sub>o</sub> = 0 to 2A     |       | 0.3           |       | %     |
| Line Regulation                | LINE <sub>REG</sub>                    | VTTIN = 3.13V to 3.47V, I <sub>o</sub> = 2A |       | 0.3           |       | %     |
| Gain (AOL) <sup>(2)</sup>      | GAIN <sub>LDO</sub>                    | LDOS Output to GATE                         |       | 50            |       | dB    |

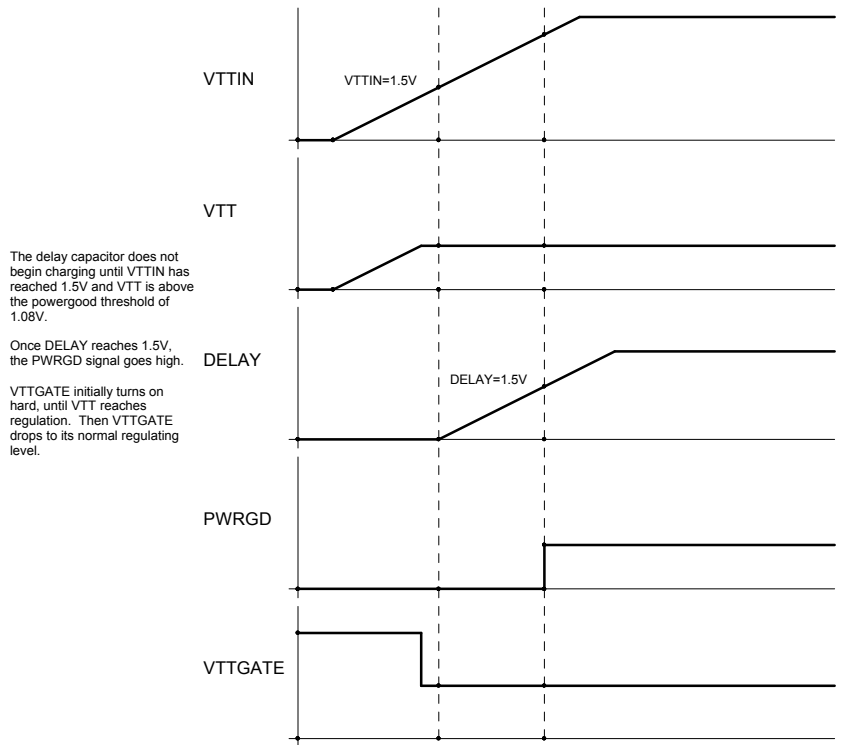
**Notes:**

- (1) All electrical characteristics are for the application circuit on page 19.
- (2) Guaranteed by design
- (3) Tracking Difference is defined as the delta between 3.3V Vin and the VTT, AGP, ADJ output voltages during the linear ramp up until regulation is achieved. The Tracking Voltage difference might vary depending on MOSFETs R<sub>dson</sub>, and Load Conditions.
- (4) During power up, an internal short circuit glitch timer will start once the VTT Input Voltage exceeds the VTTIN<sub>TH</sub> (1.5V). During the glitch timer immunity time, determined by the Delay capacitor (Delay time is approximately equal to (C<sub>delay</sub>\*SCTH)/ISC), the short circuit protection is disabled to allow VTT output to rise above the trip threshold (0.7V). If the VTT output has not risen above the trip threshold after the immunity time has elapsed, the VTT output is latched off and will only be enabled again if either the VTT input voltage or the 5VSTBY is cycled.
- (5) PWRGD pin is kept low during the power up, until the VTT output has reached its PG<sub>td1.2</sub> or PG<sub>td1.5</sub> level. At that time the PWRGD source current I<sub>PG</sub> (20uA) is enabled and will start charging the external PWRGD delay capacitor connected to the DELAY pin. Once the capacitor is charged above the PG<sub>Delay\_TH</sub> (1.5V), the PWRGD pin is released from ground.

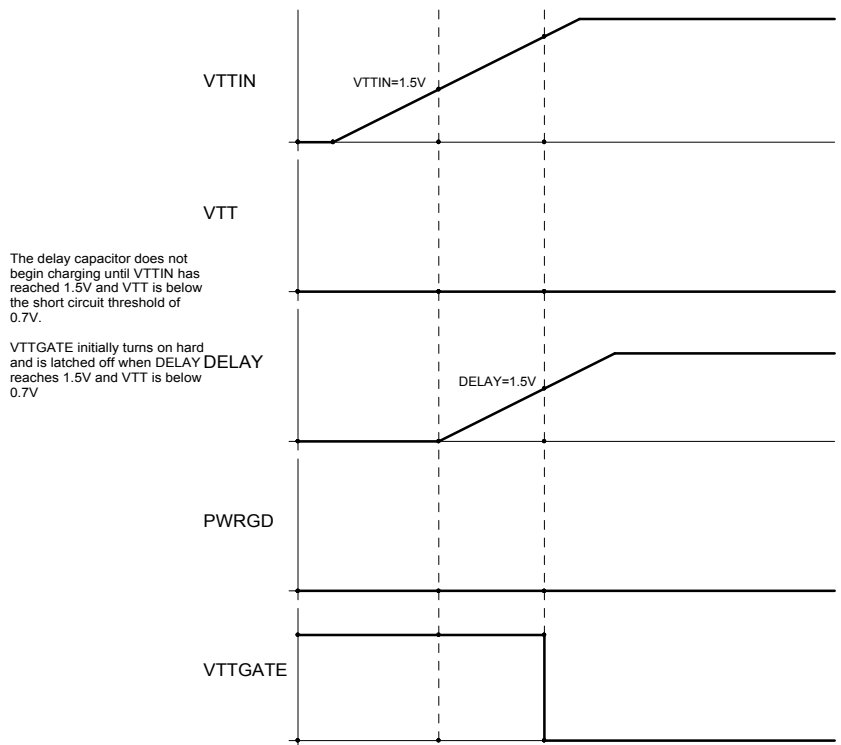
**POWER MANAGEMENT**

**Timing Diagrams**

NORMAL STARTUP CONDITION



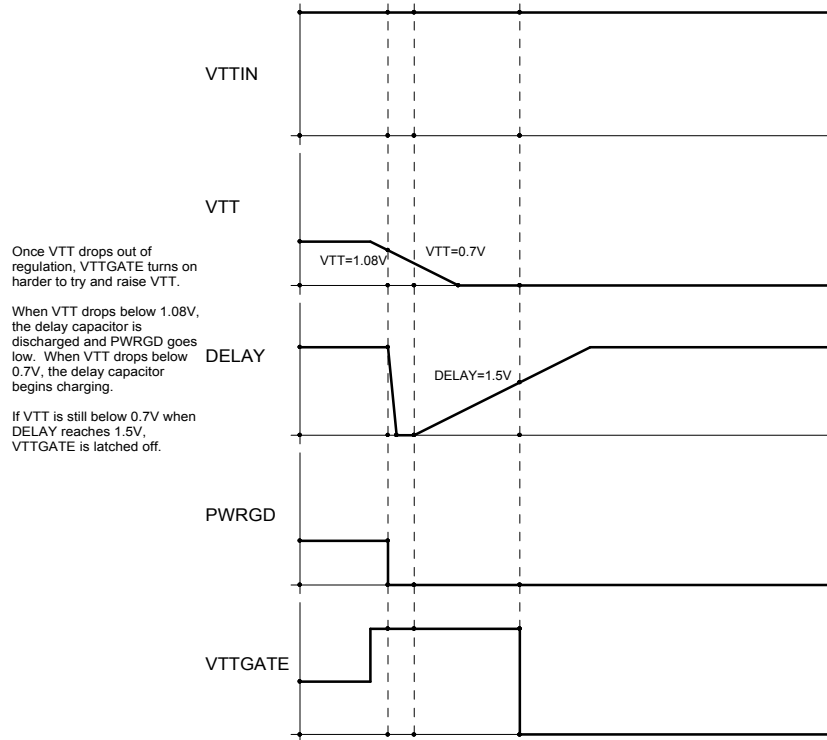
SHORT-CIRCUIT STARTUP



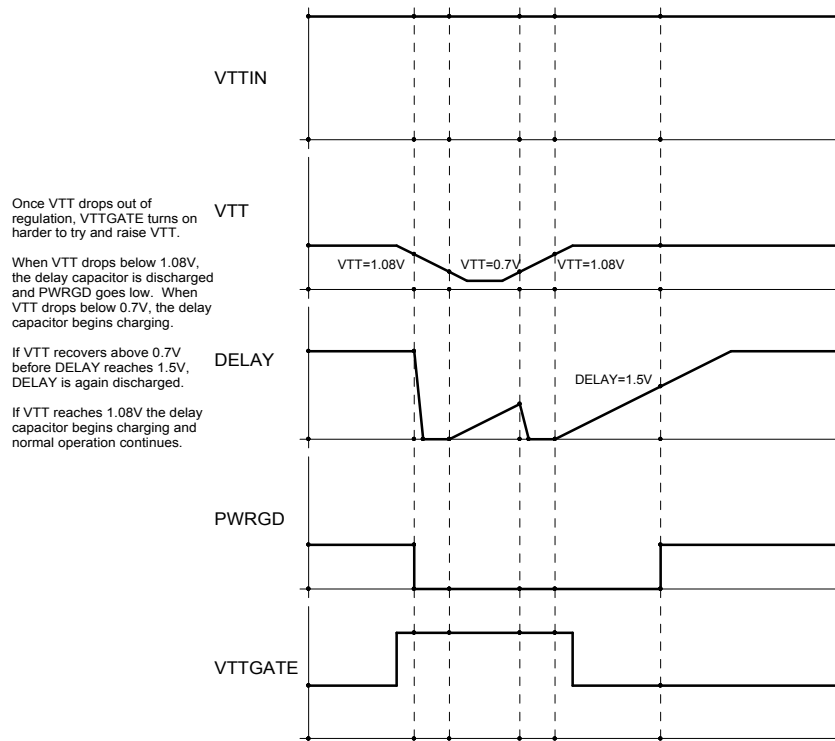
POWER MANAGEMENT

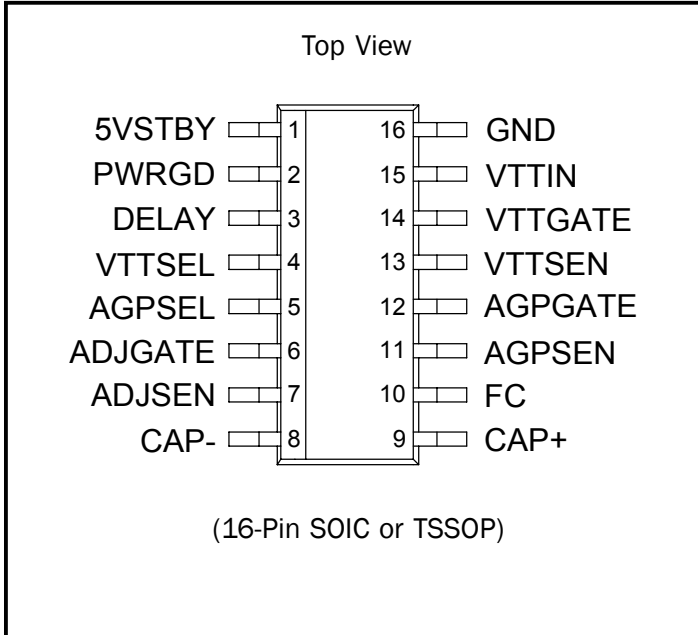
Timing Diagrams (Cont.)

SHORT-CIRCUIT DURING NORMAL OPERATION



SHORT-CIRCUIT AND RECOVERY DURING NORMAL OPERATION



**POWER MANAGEMENT**
**Pin Configuration**

**Ordering Information**

| Part Number <sup>(1)(2)</sup> | Package          | Temp Range (T <sub>J</sub> ) |
|-------------------------------|------------------|------------------------------|
| SC1112STR                     | SO-16            | 0° to 125°C                  |
| SC1112STR <sup>(3)</sup>      |                  |                              |
| SC1112ASTR                    |                  |                              |
| SC1112TSTR                    | TSSOP-16         | 0° to 125°C                  |
| SC1112TSTR <sup>(3)</sup>     |                  |                              |
| SC1112ATSTR                   |                  |                              |
| SC1112EVB                     | Evaluation Board |                              |

**Notes:**

(1) Only available in tape and reel packaging. A reel contains 2500 devices.

(2) Part Number (SO-16): SC1112STR and SC1112STR<sup>(3)</sup> = 1.25V and SC1112ASTR = 1.2V.

Part Number (TSSOP-16): SC1112TSTR = 1.25V and SC1112ATSTR = 1.2V.

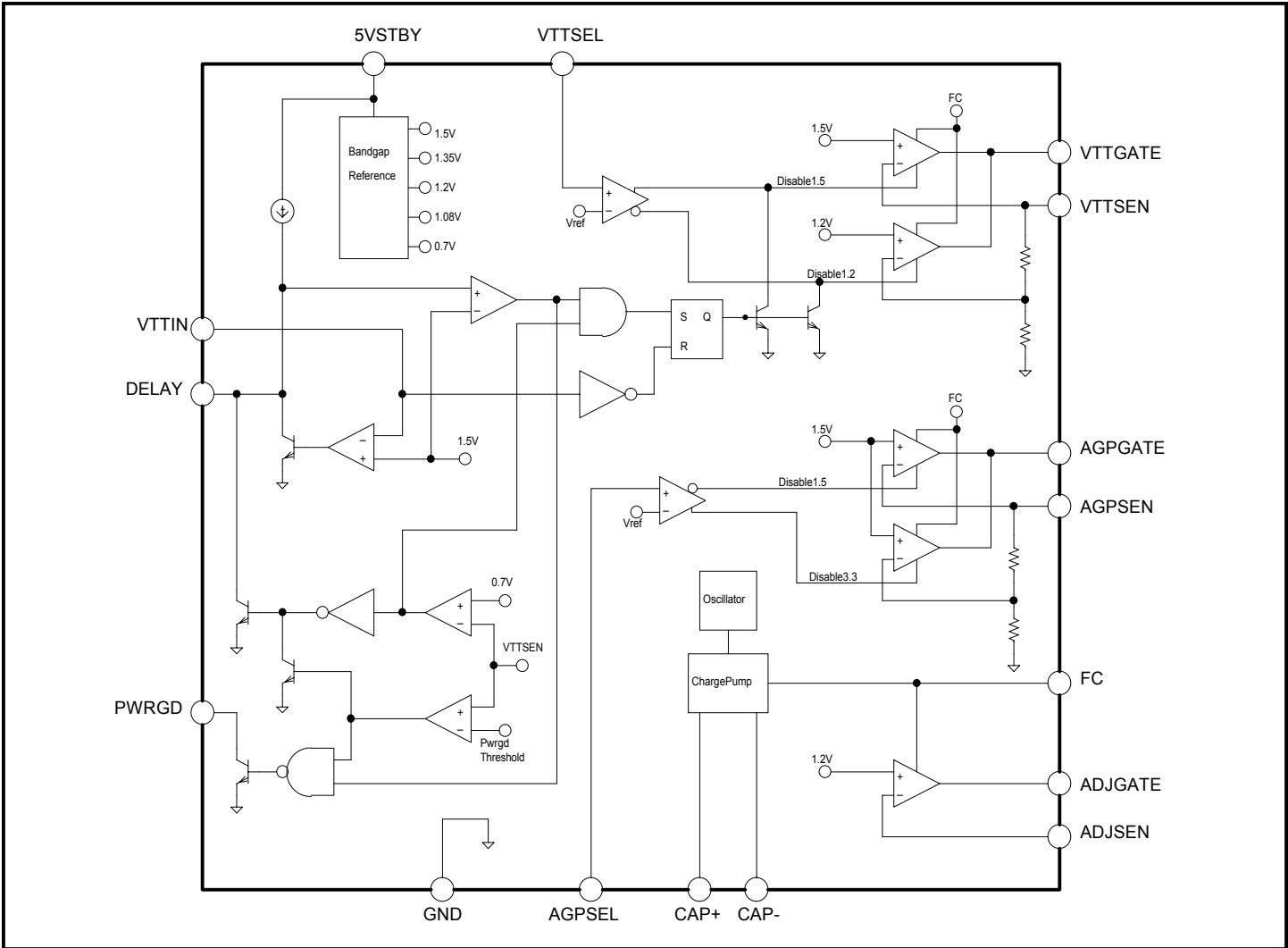
(3) Pb-free product. This product is fully WEEE and RoHS compliant.

**POWER MANAGEMENT**
**Pin Descriptions**

| Pin # | Pin Name | Pin Function  |
|-------|----------|---|
| 1     | 5VSTBY   | 5V Standby input, supplies power for Ref, Charge Pump, Oscillator and FET controllers.                                      |
| 2     | PWRGD    | Open collector Power Good Flag for VTT output.  |
| 3     | DELAY    | A capacitor from this pin to GND will program the delay for the Power Good Flag of VTT output and the glitch immunity time. |
| 4     | VTTSEL   | TTL signal that programs the VTT output voltage: VTTSEL = LOW, VTT = 1.2XV<br>VTTSEL = HIGH, VTT = 1.5V                     |
| 5     | AGPSEL   | TTL signal that programs the AGP output voltage: AGPSEL = LOW, AGP = 1.5V<br>AGPSEL = HIGH, AGP = 3.3V                      |
| 6     | ADJGATE  | Gate drive output for AGP.  |
| 7     | ADJSEN   | Sense input for ADJ.  |
| 8     | CAP-     | Negative connection to boost capacitor.   |
| 9     | CAP+     | Positive connection to boost capacitor.   |
| 10    | FC       | Filter capacitor for the internal charge pump should be connected from this pin to GND.                                     |
| 11    | AGPSEN   | Sense input for AGP.  |
| 12    | AGPGATE  | Gate drive output for AGP.  |
| 13    | VTTSEN   | Sense input for VTT.  |
| 14    | VTTGATE  | Gate drive output for VTT.  |
| 15    | VTTIN    | Short circuit sense line connected to the 3.3Vin.   |
| 16    | GND      | Ground.   |

NOTE: (1) All logic level inputs and outputs are open collector TTL compatible.

**POWER MANAGEMENT**  
Block Diagram

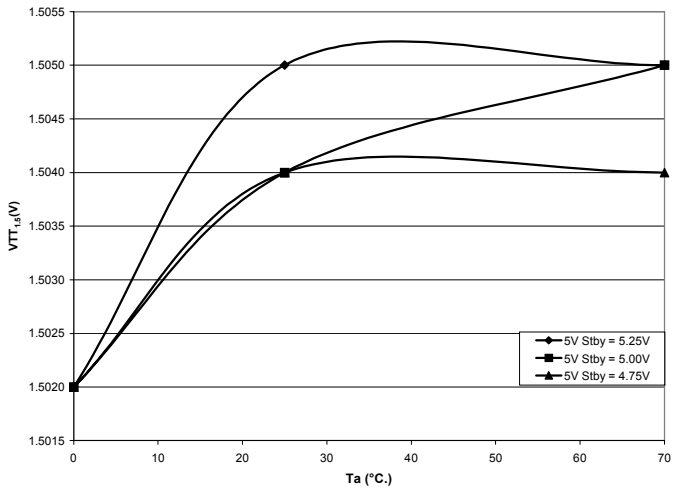




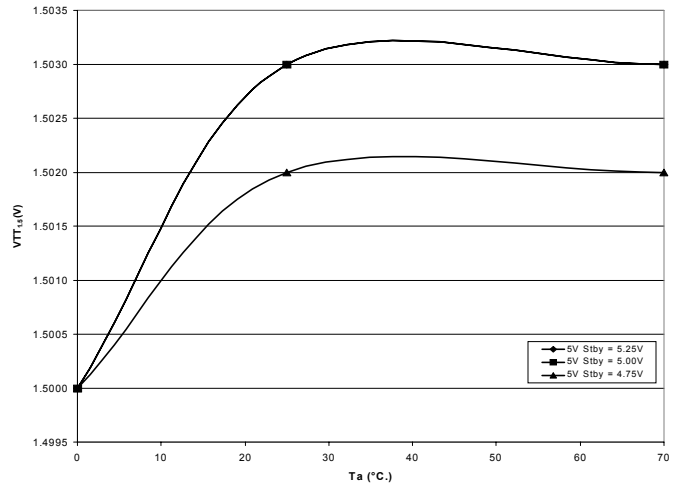
POWER MANAGEMENT

Typical Characteristics

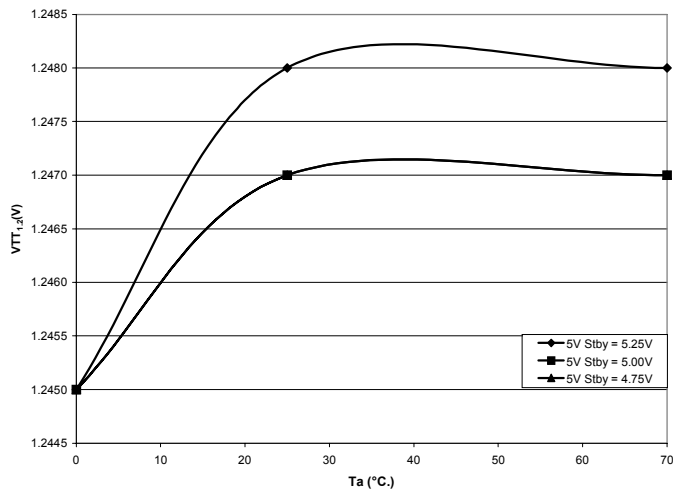
VTT(1.5V) Output Voltage @ Io = 0A vs Ta



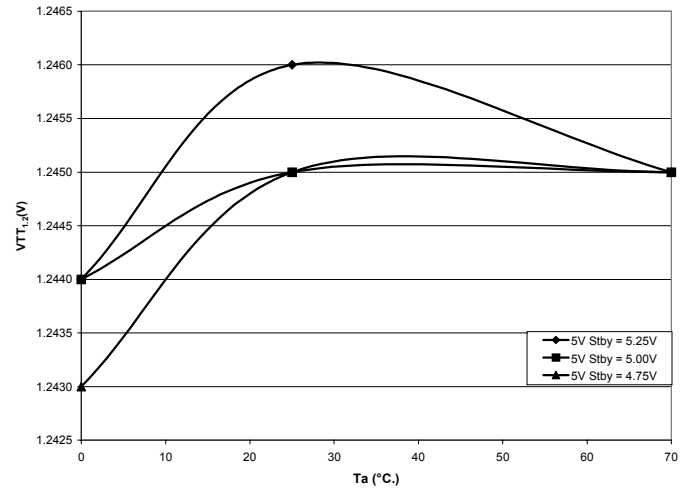
VTT(1.5V) Output Voltage @ Io = 2A vs Ta



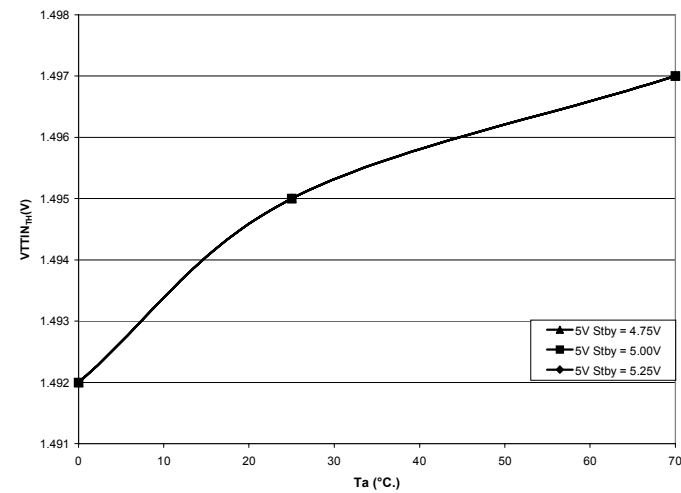
VTT(1.25V) Output Voltage @ Io = 0A vs Ta



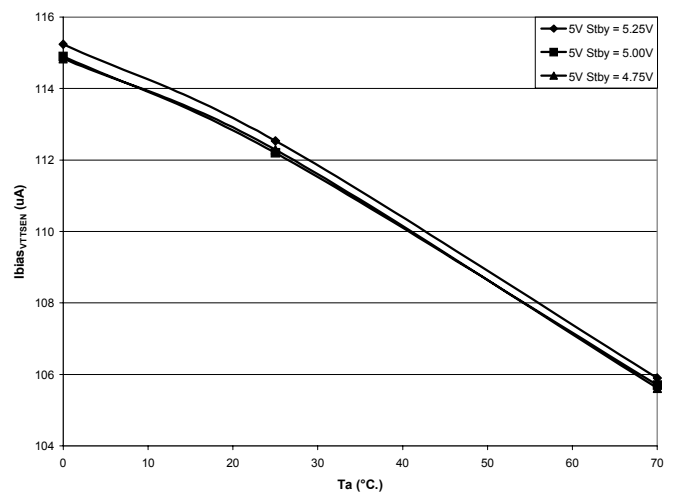
VTT(1.5V) Output Voltage @ Io = 2A vs Ta



VTT Input Supply Threshold vs Ta



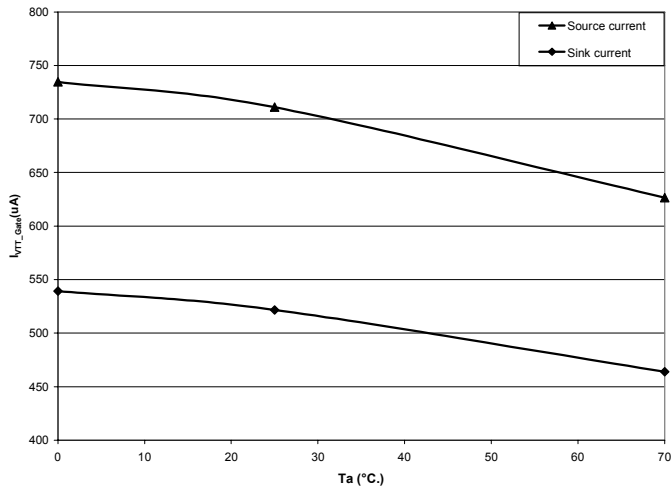
VTT Sense Bias current vs Ta



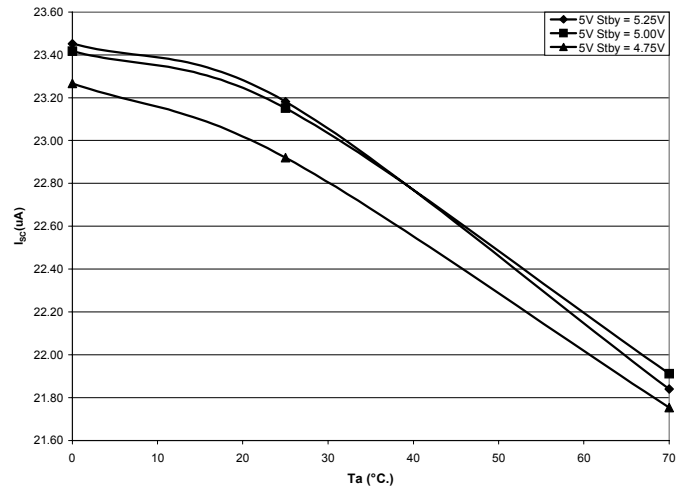
**POWER MANAGEMENT**

**Typical Characteristics (Cont.)**

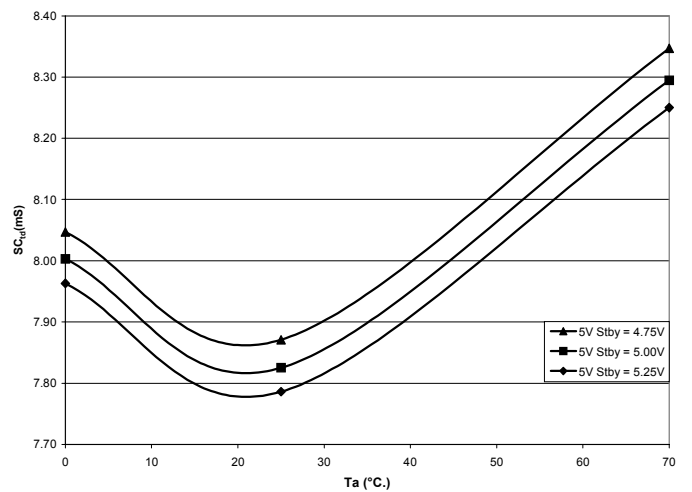
**VTT Gate Current @ Vgate = 3V, 5V Stby = 4.75V vs Ta**



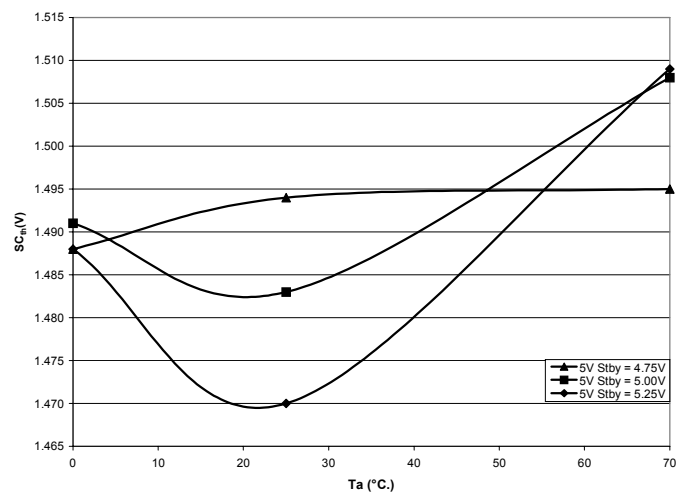
**VTT Short circuit Delay source current vs Ta**



**VTT Short circuit Delay Time (Cdelay = 0.1uF) vs Ta**



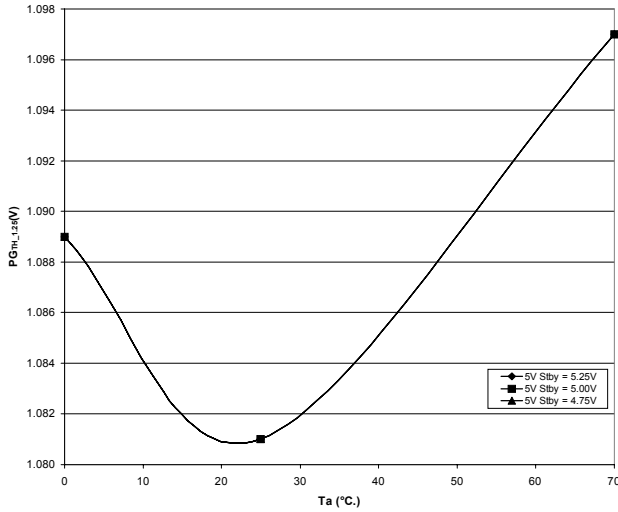
**VTT Short circuit Delay Timer Threshold vs Ta**



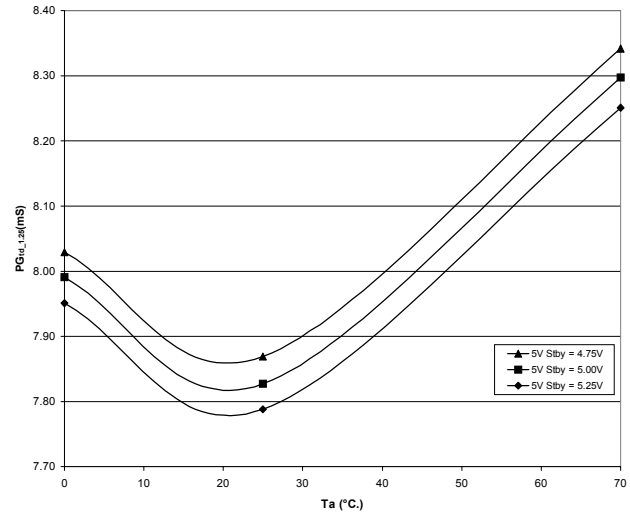
**POWER MANAGEMENT**

**Typical Characteristics (Cont.)**

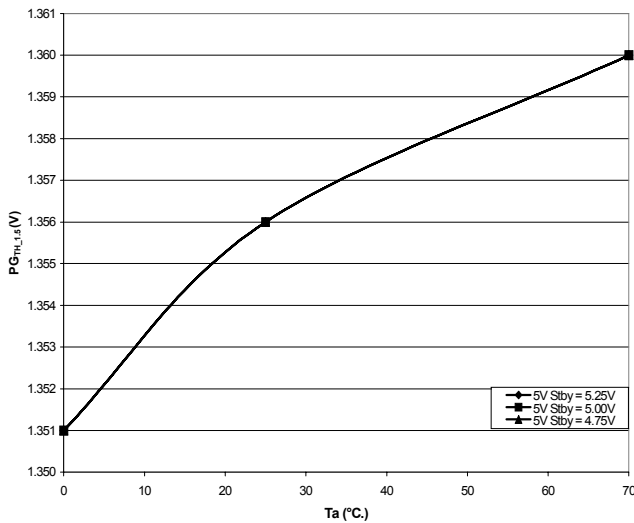
**VTT (1.25V) Power Good Threshold vs Ta**



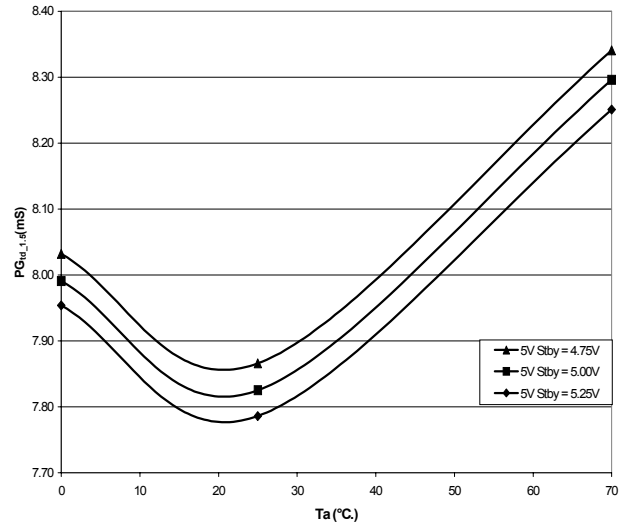
**VTT (1.25V) Power Good Delay Time vs Ta**



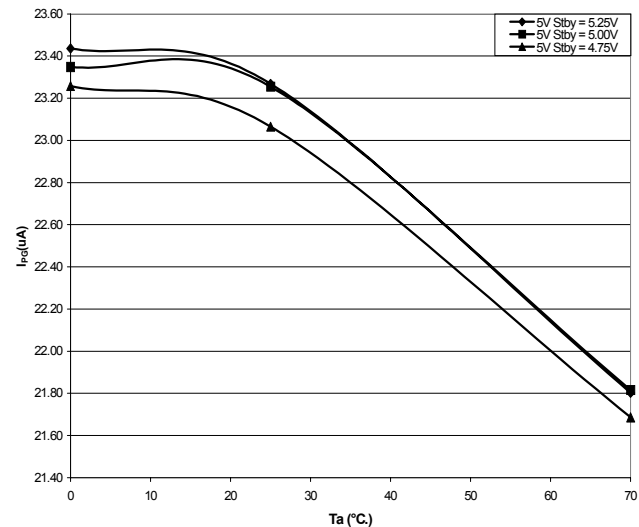
**VTT (1.5V) Power Good Threshold vs Ta**



**VTT (1.5V) Power Good Delay Time vs Ta**



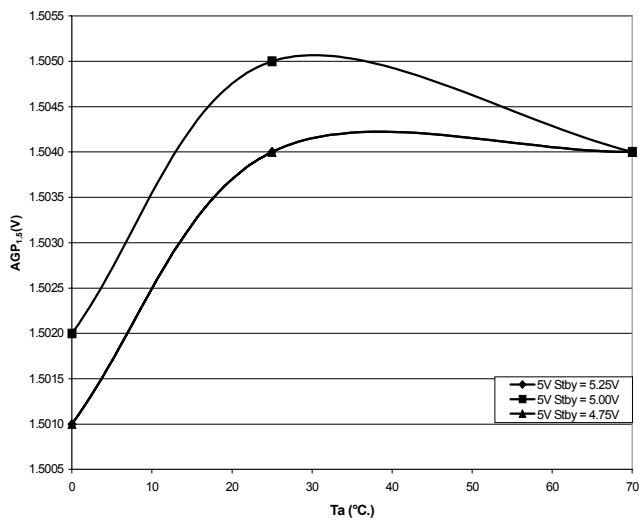
**VTT Power Good Source current vs Ta**



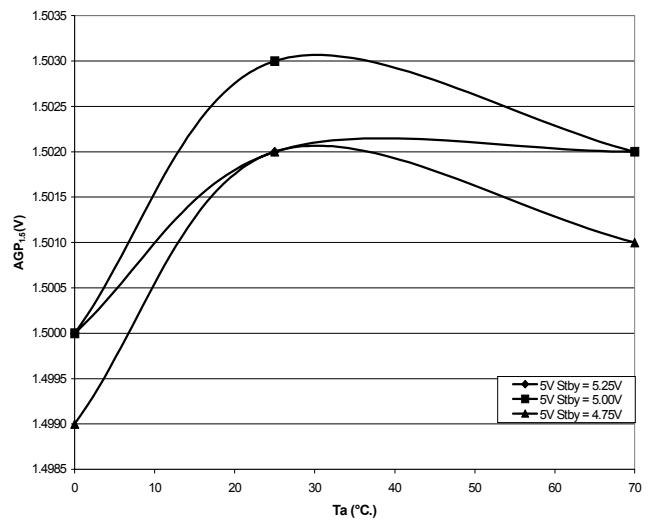
**POWER MANAGEMENT**

**Typical Characteristics (Cont.)**

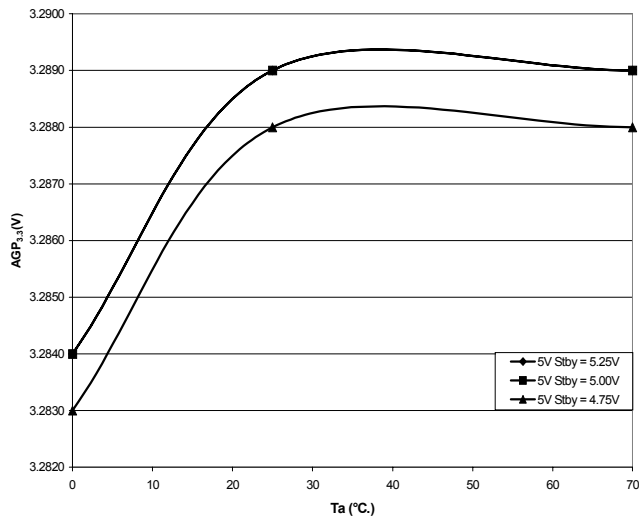
**AGP (1.5V) Output Voltage @  $I_o = 0A$  vs  $T_a$**



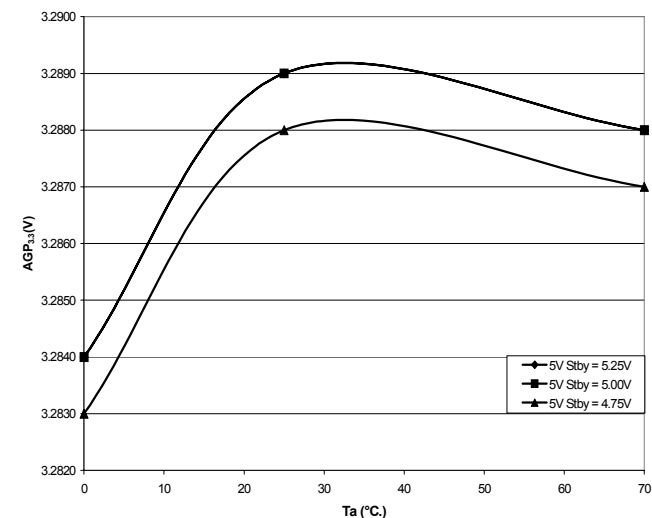
**AGP (1.5V) Output Voltage @  $I_o = 2A$  vs  $T_a$**



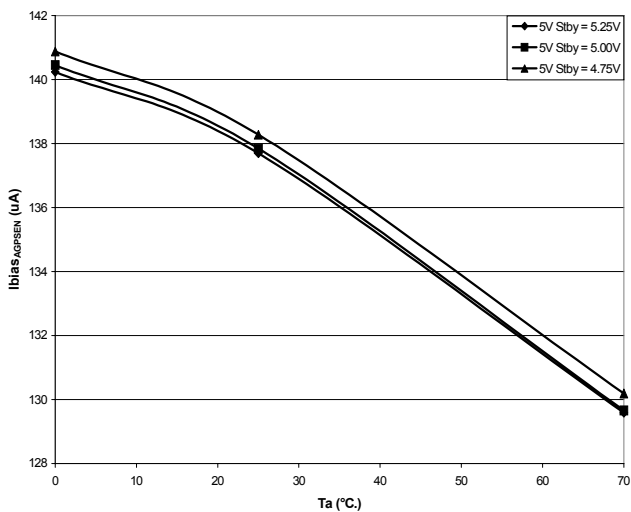
**AGP (3.3V) Output Voltage @  $I_o = 0A$  vs  $T_a$**



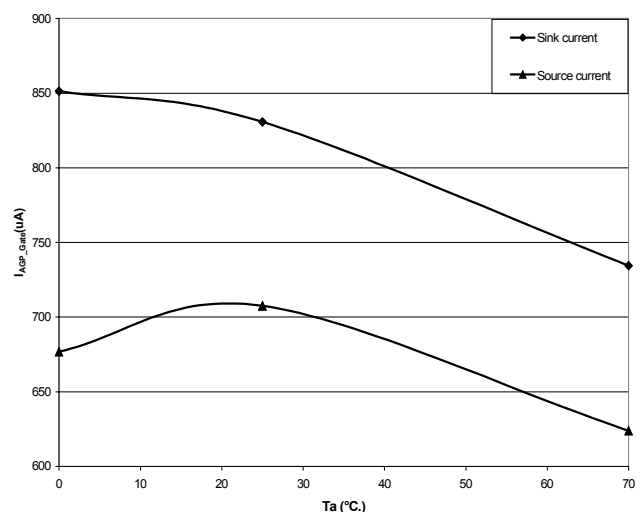
**AGP (3.3V) Output Voltage @  $I_o = 2A$  vs  $T_a$**



**AGP Sense Bias current vs  $T_a$**



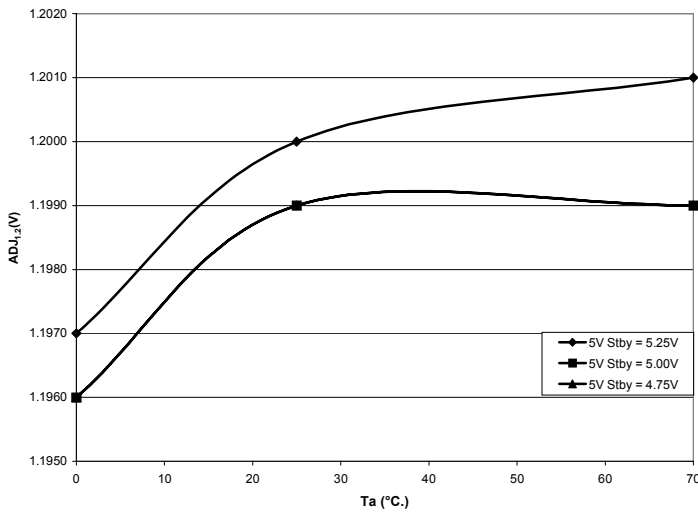
**AGP Gate Current @  $V_{gate} = 3V$ , 5V Stby = 4.75 vs  $T_a$**



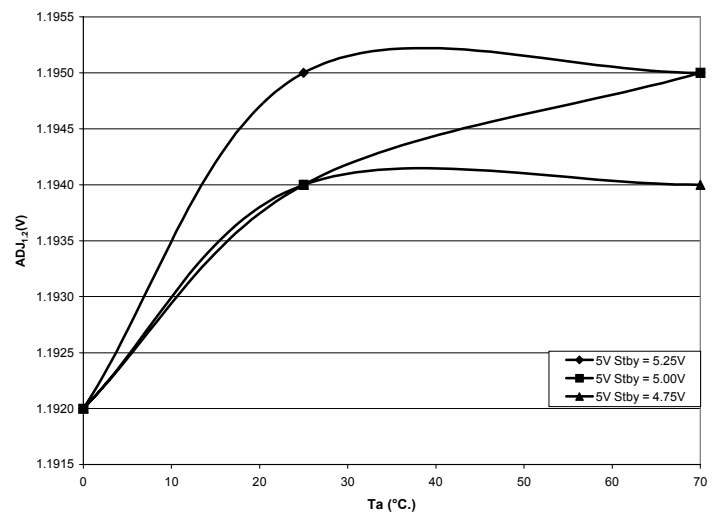
POWER MANAGEMENT

Typical Characteristics (Cont.)

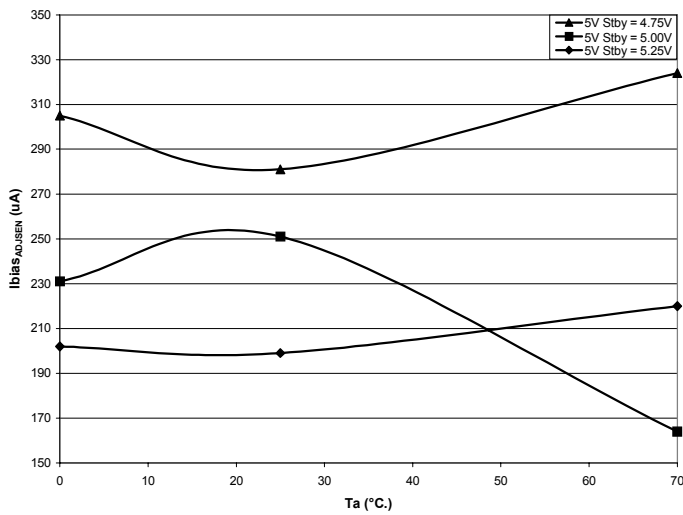
ADJ (1.2V) Output Voltage @  $I_o = 0A$  vs  $T_a$



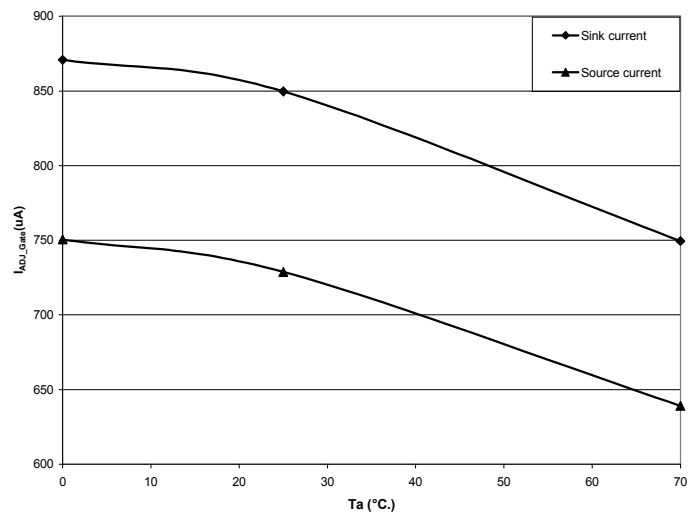
ADJ (1.2V) Output Voltage @  $I_o = 2A$  vs  $T_a$



ADJ Sense Bias current vs  $T_a$

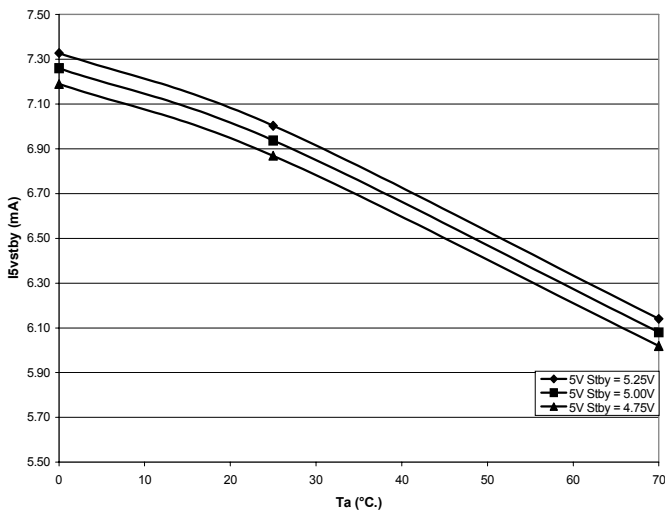


ADJ Gate Current @  $V_{gate} = 3V$ , 5V Stby = 4.75V vs  $T_a$

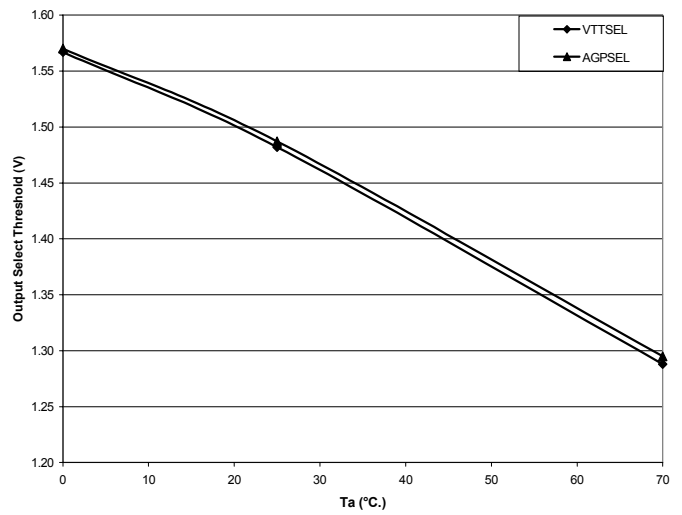


**POWER MANAGEMENT**  
**Typical Characteristics (Cont.)**

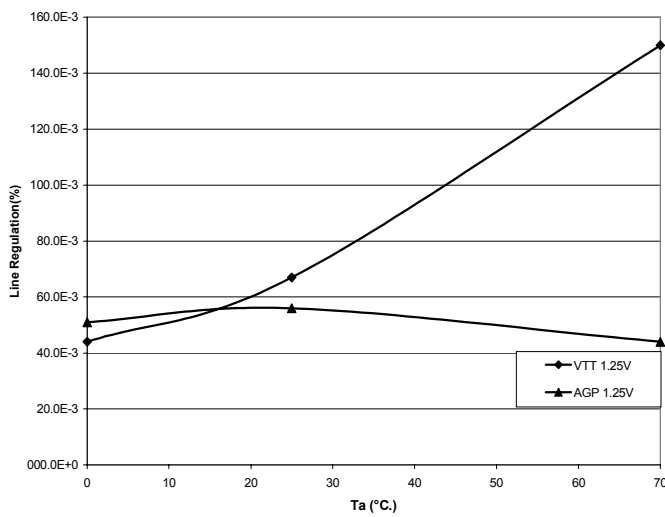
**I 5V Stby vs Ta**



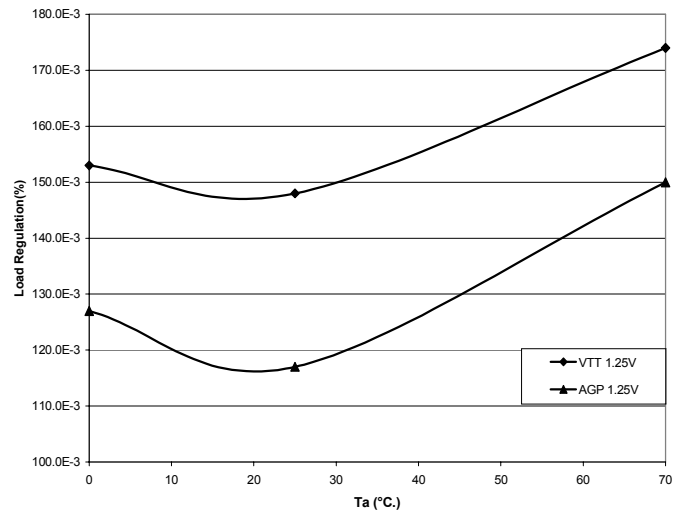
**Output Select Threshold vs Ta**



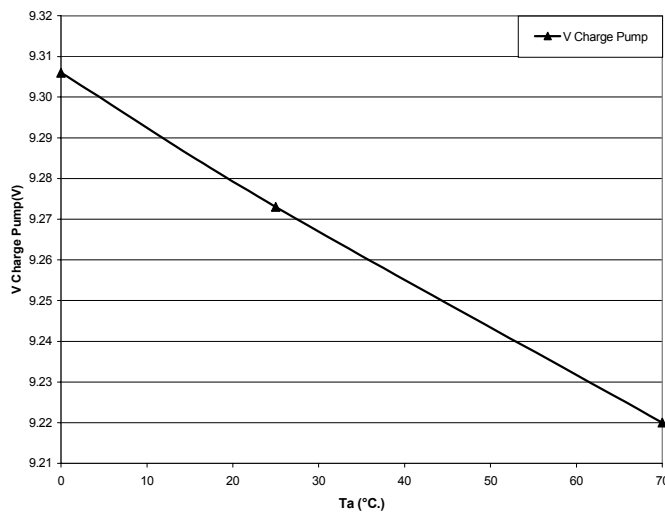
**Line Regulation VTTIN = 3.13V to 3.47V Io = 2A vs Ta**



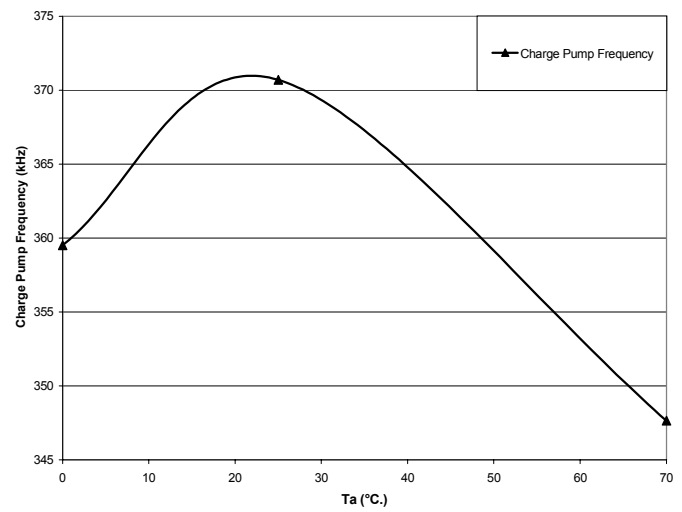
**Load Regulation VTTIN = 3.3V Io = 0 to 2A vs Ta**

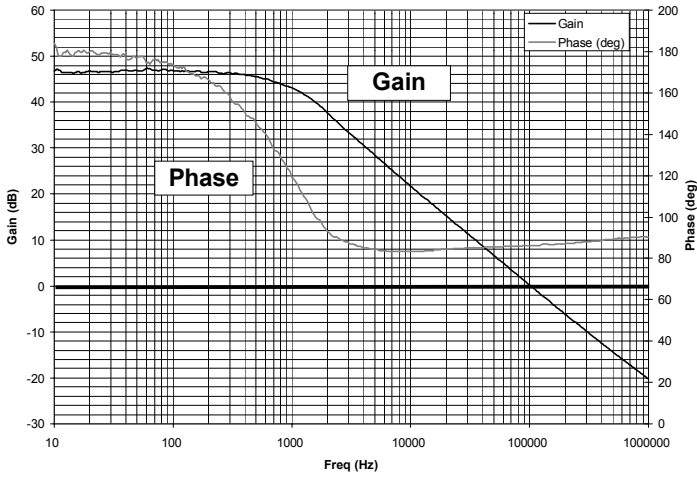
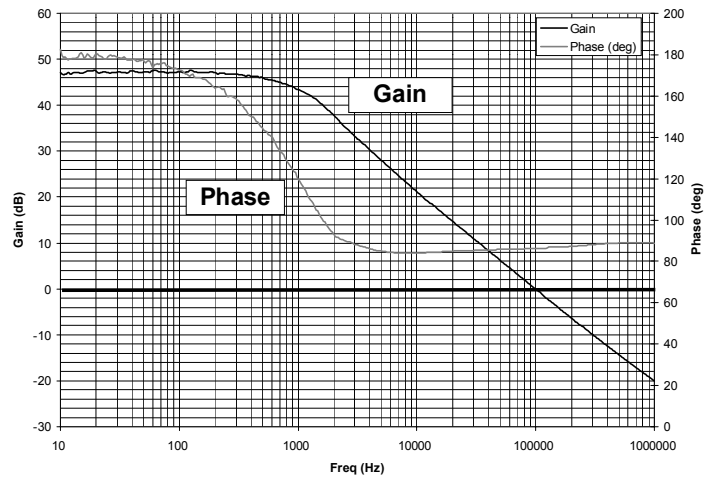
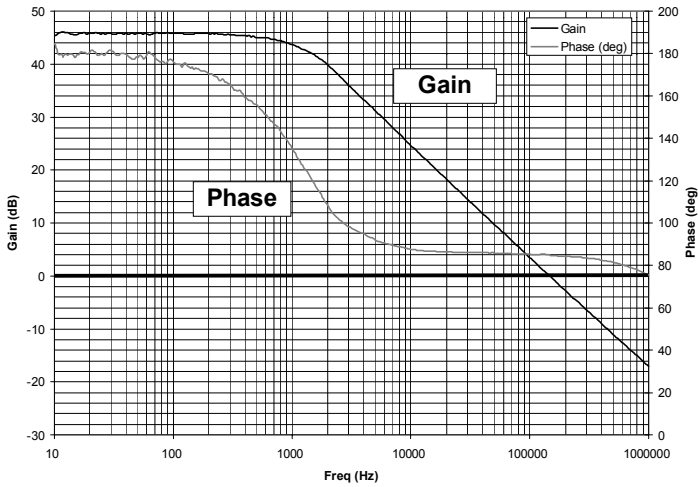
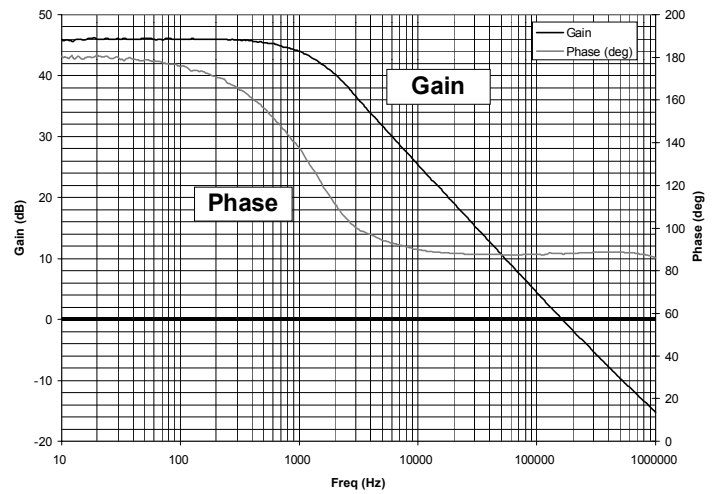


**Charge Pump Output Voltage vs Ta**



**Charge Pump Frequency vs Ta**



**POWER MANAGEMENT**
**Typical Gain & Phase Margin**
**SC1112 Gain / Phase VTT = 1.25V @ 2A**

**SC1112 Gain / Phase VTT = 1.5V @ 2A**

**SC1112 Gain / Phase ADJ = 1.2V @ 2A**

**SC1112 Gain / Phase AGP = 1.5V @ 2A**


**POWER MANAGEMENT**
**Applications Information**
**Theory Of Operation**

The SC1112 was designed for the latest high speed mother boards requiring a controlled power up sequencing of the Outputs, and a programmable delay for the Power good signal.

Three Linear controllers have been incorporated into the SC1112. The VTT output can be programmed to either a 1.250V or a 1.500V by applying a LOW or a HIGH control signal to the VTTSEL pin. AGP output can also be programmed via AGPSEL pin to a 1.50V or a 3.30V. The SC1112 also provides an Adjustable output which utilizes a resistive voltage divider.

The +5VSTBY supply will power the internal Reference, Charge Pump, Oscillator, and the Fet controllers. After the +5VSTBY has been established, LDO outputs will track the VTTIN (3.30V) supply as it is applied.

An external capacitor connected to the Delay pin will program the VTT short circuit delay time ( $SC_{td}$ ), and the PWRGD delay time ( $PG_{td}$ ).

During power up, an internal short circuit glitch timer will start once the VTT Input Voltage exceeds the  $VTTIN_{TH}$  (1.5V). During the glitch timer immunity time, determined by the Delay capacitor (Delay time is approximately equal to  $(C_{delay} \cdot S_{CTH}) / ISC$ ), the short circuit protection is disabled to allow VTT output to rise above the trip threshold (0.7V).

If the VTT output has not risen above the trip threshold after the immunity time has elapsed, the VTT output is latched off and will only be enabled again if either the VTT input voltage or the 5VSTBY is cycled.

PWRGD pin is kept low during the power up, until the VTT output has reached its  $PG_{td1.25}$  or  $PG_{td1.5}$  level. At that time the PWRGD source current  $I_{pg}$  (20uA) is enabled and will start charging the external PWRGD delay capacitor connected to the DELAY pin. Once the capacitor is charged above the  $PG_{Delay\_TH}$  (1.5V), the PWRGD pin is released from ground. A detailed timing diagram is shown on pages 4 to 5.

Also included is an overcurrent protection circuit that monitors the VTT voltage. If the output voltage drops below 700mV, as would occur during an overcurrent or short condition, the device will pull the drive pin low and latch off the output.

**Fixed Output Voltage Options (VTT, AGP)**

Please refer to the Application Circuit on Page 1. The VTT and the AGP fixed output voltage can be programmed from a Control logic signal. Table below shows the possible voltages:

| VTTSEL | AGPSEL | VTT   | AGP   |
|--------|--------|-------|-------|
| 0      | 0      | 1.25V | 1.50V |
| 0      | 1      | 1.25V | 3.30V |
| 1      | 0      | 1.50V | 1.50V |
| 1      | 1      | 1.50V | 3.30V |

Once the VTTSEL or the AGPSEL signal is established, an internal resistive divider is used to compare the bandgap reference voltage with the feedback output voltage. The drive pin voltage is then adjusted to maintain the output voltage set by the internal resistor divider. Referring to the block diagram on page 8.

It is possible to adjust the output voltage of the VTT or AGP, by applying an external resistor divider to the sense pin (please refer to Figure 1 on Page 17). Since the sense pin sinks a nominal 100uA, the resistor values should be selected to allow 10mA to flow through the divider. This will ensure that variations in this current do not adversely affect output voltage regulation. Thus a target value for R2 (maximum) can be calculated:

$$R2 \leq \frac{V_{OUT(FIXED)}}{10mA} \quad \Omega$$

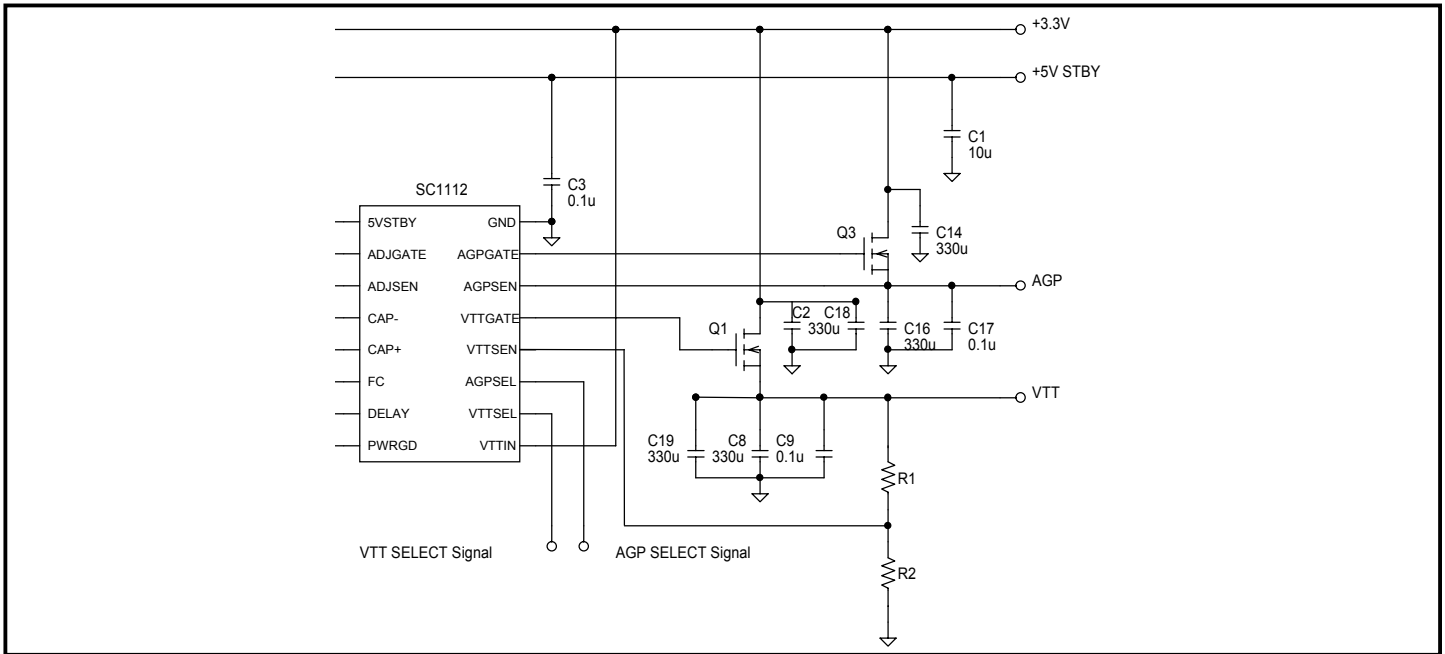
The output voltage can only be adjusted upwards from the fixed output voltage, and can be calculated using the following equation:

$$V_{OUT(ADJUSTED)} = V_{OUT(FIXED)} \cdot \left(1 + \frac{R1}{R2}\right) + R1 \cdot 100 \mu A \quad \text{Volts}$$



**POWER MANAGEMENT**

**Applications Information (Cont.)**



**Figure 1: Adjusting The Output Voltage of VTT or AGP**

**Adjustable Output Voltage Option**

The adjustable output voltage option does not have an internal resistor divider. The adjust pin connects directly to the inverting input of the error amplifier, and the output voltage is set using external resistors (please refer to Figure 2). In this case, the adjust pin sources a nominal 0.5µA, so the resistor values should be selected to allow 50µA to flow through the divider. Again, a target value for RB (maximum) can be calculated:

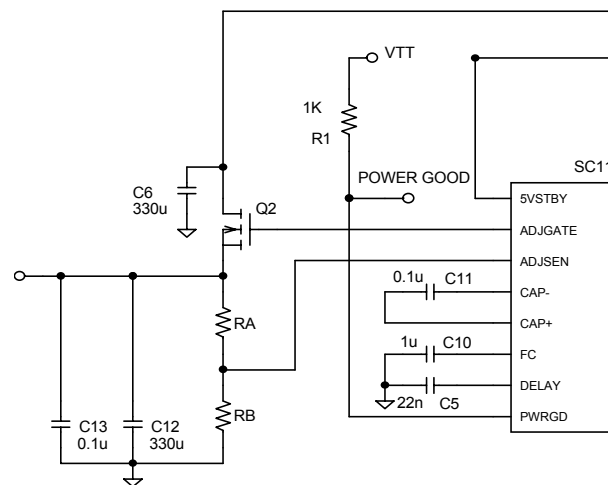
$$R_B \leq \frac{1.200 \text{ V}}{50 \mu\text{A}} \quad \Omega$$

The output voltage can be calculated as follows:

$$V_{OUT} = 1.200 \cdot \left(1 + \frac{R_A}{R_B}\right) - 0.5 \mu\text{A} \cdot R_A$$

The maximum output voltage that can be obtained from the adjustable option is determined by the input supply voltage and the  $R_{DS(ON)}$  and gate threshold voltage of the external MOSFET. Assuming that the MOSFET gate threshold voltage is sufficiently low for the output voltage chosen and a worst-case drive voltage of 9V,  $V_{OUT(MAX)}$  is given by:

$$V_{OUT(MAX)} = VTTIN_{(MIN)} - I_{OUT(MAX)} \cdot R_{DS(ON)(MAX)}$$



**Figure 2**

**POWER MANAGEMENT**
**Applications Information (Cont.)**
**Short Circuit Protection**

The VTT short circuit protection feature of the SC1112 is implemented by using the  $R_{DS(ON)}$  of the MOSFET. As the output current increases, the regulation loop maintains the output voltage by turning the FET on more and more. Eventually, as the  $R_{DS(ON)}$  limit is reached, the MOSFET will be unable to turn on any further, and the output voltage will start to fall. When the VTT output voltage falls to approximately 700mV, the LDO controller is latched off, setting output voltage to 0V. Power must be cycled to reset the latch.

To prevent false latching due to capacitor inrush currents or low supply rails, the current limit latch is initially disabled. It is enabled once the short circuit delay time has elapsed. Timing diagram on pages 4 to 5 will show a detailed operation of the Short Circuit protection circuitry.

To be most effective, the MOSFET  $R_{DS(ON)}$  should not be selected artificially low. The MOSFET should be chosen so that at maximum required current, it is almost fully turned on. If, for example, a supply of 1.5V at 4A is required from a  $3.3V \pm 5\%$  rail, the maximum allowable  $R_{DS(ON)}$  would be:

$$R_{DS(ON)(MAX)} = \frac{(0.95 \cdot 3.3 - 1.5 \cdot 1.025)}{4} \approx 400 \text{ m}\Omega$$

To allow for temperature effects 200m $\Omega$  would be a suitable room temperature maximum, allowing a peak short circuit current of approximately 15A for a short time before shutdown.

**Capacitor Selection**

**Output Capacitors:** Low ESR aluminum electrolytic or tantalum capacitors are recommended for bulk capacitance, with ceramic bypass capacitors for decoupling high frequency transients.

**Input Capacitors:** Placement of low ESR aluminum electrolytic or tantalum capacitors at the input to the MOSFET (VTTIN) will help to hold up the power supply during fast load changes, thus improving overall transient response. The +5VSTBY supply should be bypassed with a 10 $\mu$ F ceramic capacitor.

**Layout Guidelines**

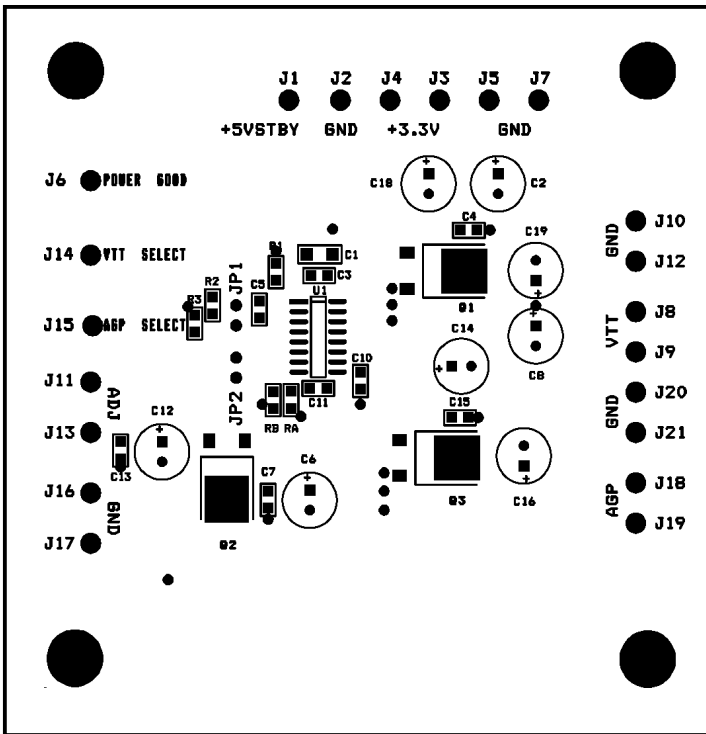
One of the advantages of using the SC1112 to drive an external MOSFET is that the bandgap reference and control circuitry do not need to be located right next to the power device, thus a very accurate output voltage can be obtained since heating effects will be minimal.

The 0.1 $\mu$ F bypass capacitor should be located close to the +5VSTBY supply pin, and connected directly to the ground plane. The ground pin of the device should also be connected directly to the ground plane. The sense or adjust pin does not need to be close to the output voltage plane, but should be routed to avoid noisy traces if at all possible.

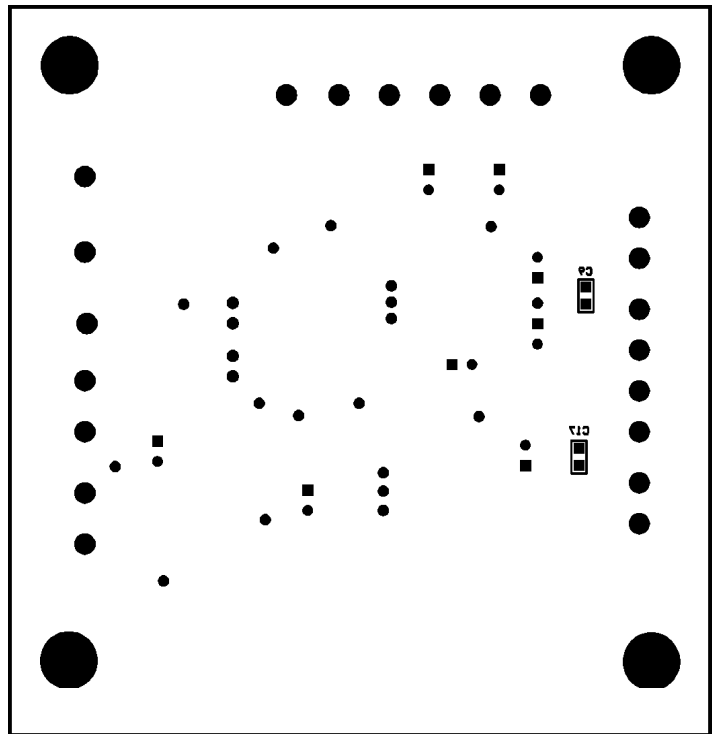
Power dissipation within the device is practically negligible, requiring no special consideration during layout.

**POWER MANAGEMENT**

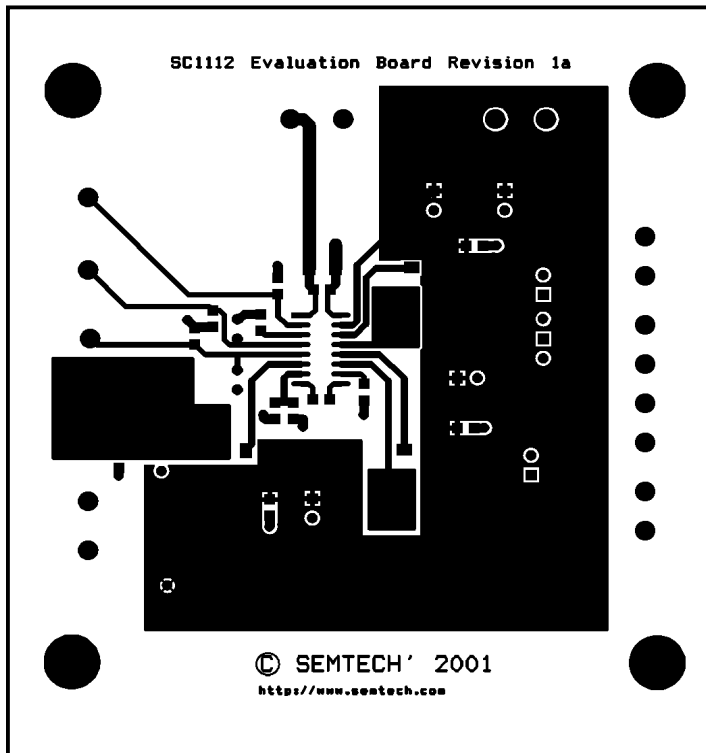
**Evaluation Board Gerbers**



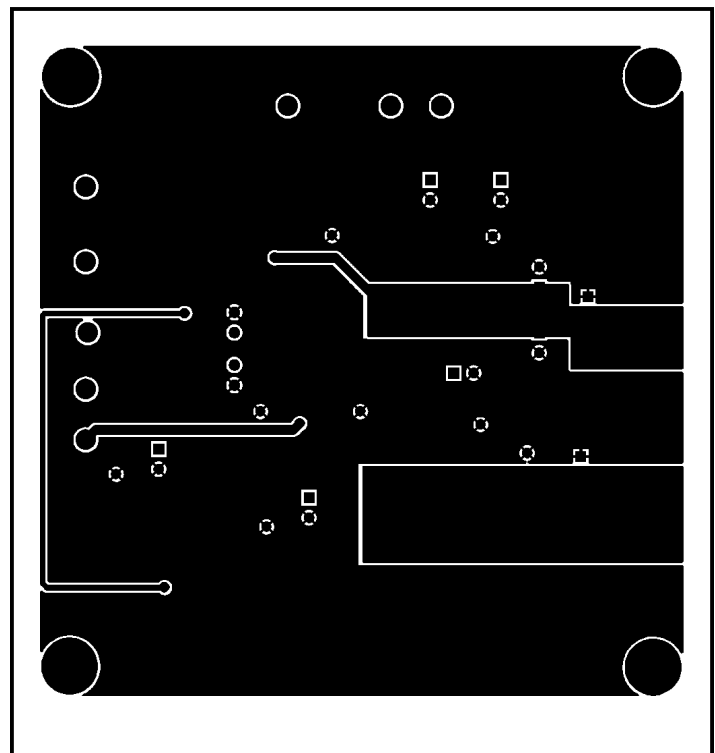
**Board Layout Assembly Top**



**Board Layout Assembly Bottom**



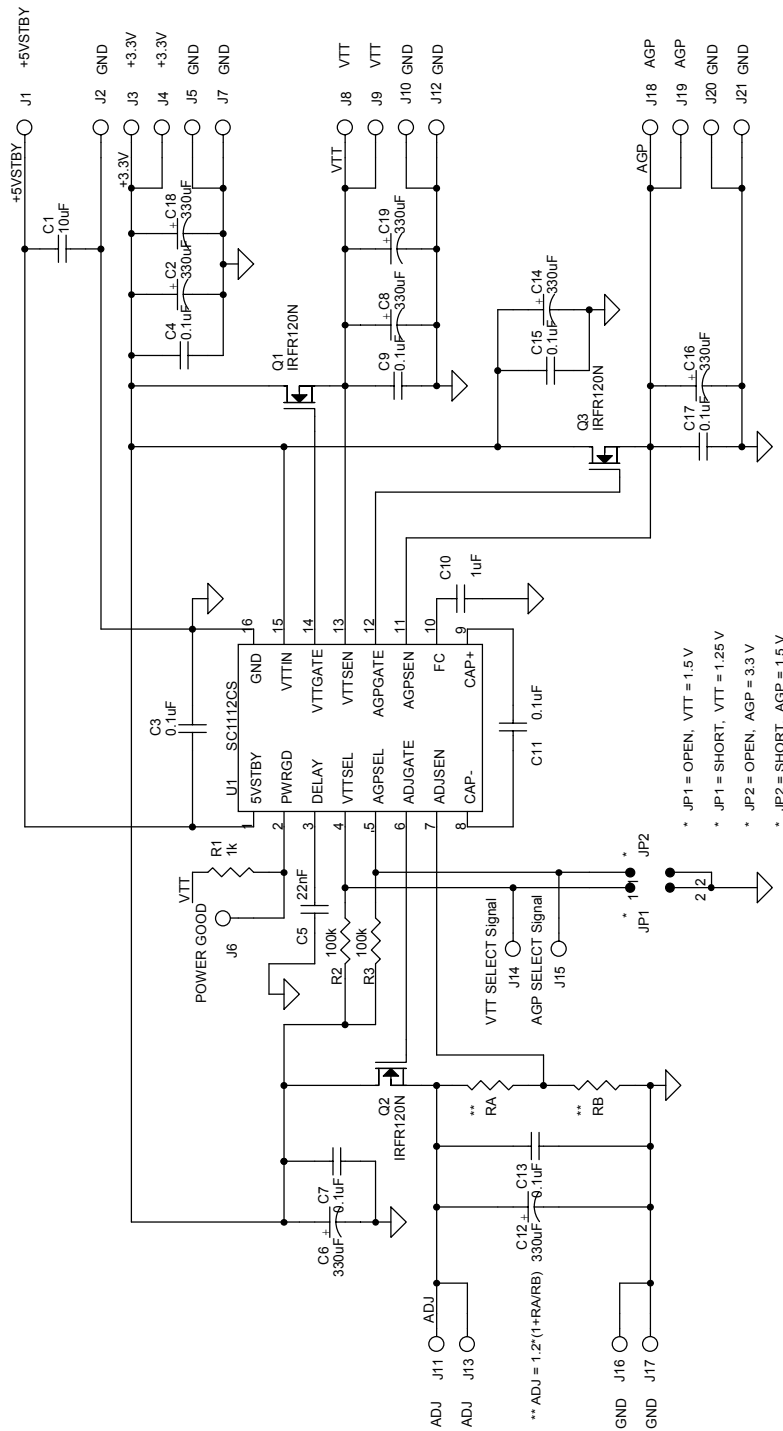
**Board Layout Top**



**Board Layout Bottom**

POWER MANAGEMENT

Evaluation Board Schematic

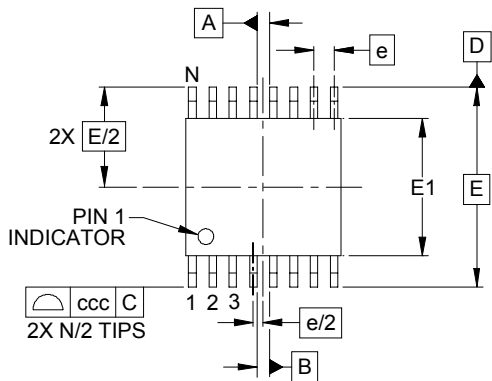


**POWER MANAGEMENT**
**Evaluation Board Bill of Materials**

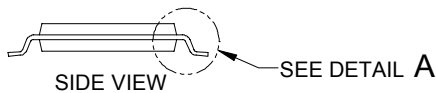
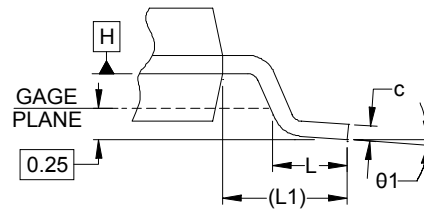
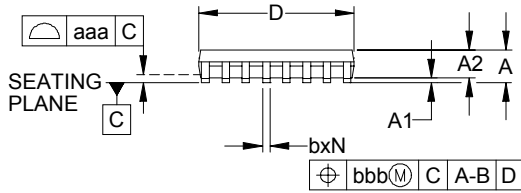
| Item | Qty. | Reference                        | Part              | Foot Print               |
|------|------|----------------------------------|-------------------|--------------------------|
| 1    | 1    | C1                               | 10uF              | 1206                     |
| 2    | 8    | C2,C6,C8,C12,C14,C16,C18,C19     | 330uF             | CPCYL/D.2.75/LS.100/.031 |
| 3    | 8    | C3,C4,C7,C9,C11,C13,C15,C17      | 0.1uF             | 0805                     |
| 4    | 1    | C5                               | 22nF              | 0805                     |
| 5    | 1    | C10                              | 1uF               | 0805                     |
| 6    | 2    | JP1,JP2                          | TP2               | VIA/2P                   |
| 7    | 1    | J1                               | +5VSTBY           | ED5052                   |
| 8    | 9    | J2,J5,J7,J10,J12,J16,J17,J20,J21 | GND               | ED5052                   |
| 9    | 2    | J3,J4                            | +3.3V             | ED5052                   |
| 10   | 1    | J6                               | Power Good        | ED5052                   |
| 11   | 2    | J8,J9                            | VTT               | ED5052                   |
| 12   | 2    | J11,J12                          | ADJ               | ED5052                   |
| 13   | 1    | J14                              | VTT SELECT Signal | ED5052                   |
| 14   | 1    | J15                              | AGP SELECT Signal | ED5052                   |
| 15   | 2    | J18,J19                          | AGP               | ED5052                   |
| 16   | 3    | Q1,Q2,Q3                         | IRFR120N          | DPAKFET                  |
| 17   | 3    | R1,RA,RB                         | 1k                | 0805                     |
| 18   | 2    | R2,R3                            | 100k              | 0805                     |
| 19   | 1    | U1                               | SC1112STRT        | SO-16                    |

**POWER MANAGEMENT**

**Outline Drawing - TSSOP-16**



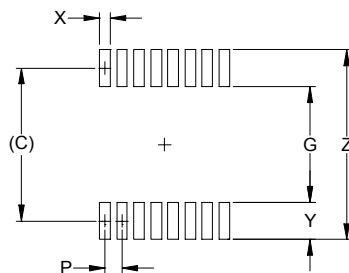
| DIM | INCHES   |      |      | MILLIMETERS |      |      |
|-----|----------|------|------|-------------|------|------|
|     | MIN      | NOM  | MAX  | MIN         | NOM  | MAX  |
| A   | -        | -    | .047 | -           | -    | 1.20 |
| A1  | .002     | -    | .006 | 0.05        | -    | 0.15 |
| A2  | .031     | -    | .042 | 0.80        | -    | 1.05 |
| b   | .007     | -    | .012 | 0.19        | -    | 0.30 |
| c   | .003     | -    | .007 | 0.09        | -    | 0.20 |
| D   | .192     | .196 | .201 | 4.90        | 5.00 | 5.10 |
| E1  | .169     | .173 | .177 | 4.30        | 4.40 | 4.50 |
| E   | .252 BSC |      |      | 6.40 BSC    |      |      |
| e   | .026 BSC |      |      | 0.65 BSC    |      |      |
| L   | .018     | .024 | .030 | 0.45        | 0.60 | 0.75 |
| L1  | ( .039 ) |      |      | ( 1.0 )     |      |      |
| N   | 16       |      |      | 16          |      |      |
| θ1  | 0°       | -    | 8°   | 0°          | -    | 8°   |
| aaa | .004     |      |      | 0.10        |      |      |
| bbb | .004     |      |      | 0.10        |      |      |
| ccc | .008     |      |      | 0.20        |      |      |



**NOTES:**

1. CONTROLLING DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGREES).
2. DATUMS **-A-** AND **-B-** TO BE DETERMINED AT DATUM PLANE **-H-**.
3. DIMENSIONS "E1" AND "D" DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
4. REFERENCE JEDEC STD MO-153, VARIATION AB.

**Land Pattern - TSSOP-16**



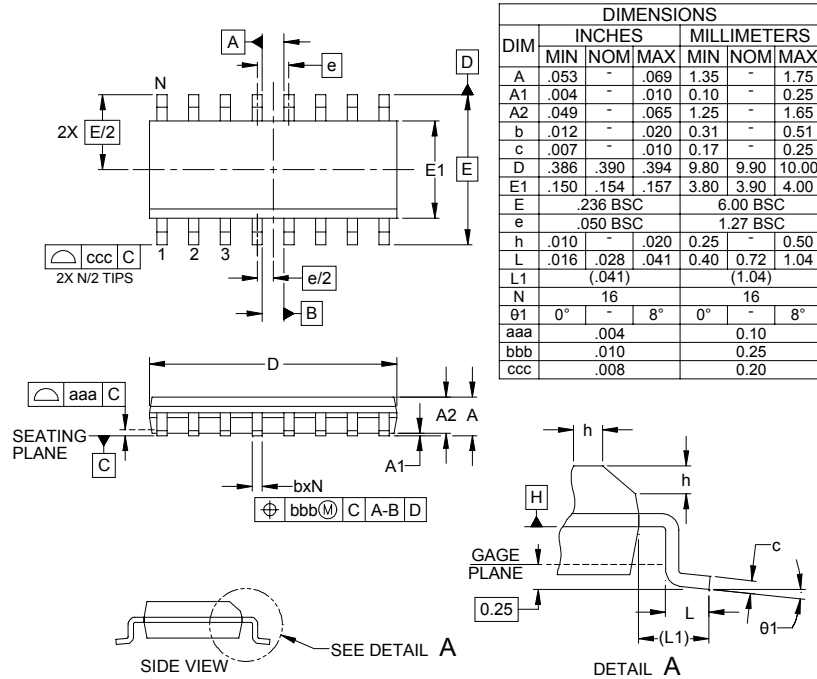
| DIM | DIMENSIONS |             |
|-----|------------|-------------|
|     | INCHES     | MILLIMETERS |
| C   | (.222)     | (5.65)      |
| G   | .161       | 4.10        |
| P   | .026       | 0.65        |
| X   | .016       | 0.40        |
| Y   | .061       | 1.55        |
| Z   | .283       | 7.20        |

**NOTES:**

1. THIS LAND PATTERN IS FOR REFERENCE PURPOSES ONLY. CONSULT YOUR MANUFACTURING GROUP TO ENSURE YOUR COMPANY'S MANUFACTURING GUIDELINES ARE MET.

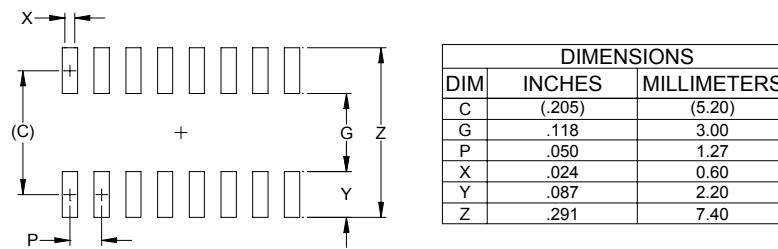
**POWER MANAGEMENT**

**Outline Drawing - SO-16**



- NOTES:
1. CONTROLLING DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGREES).
  2. DATUMS [-A-] AND [-B-] TO BE DETERMINED AT DATUM PLANE [-H-].
  3. DIMENSIONS "E1" AND "D" DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
  4. REFERENCE JEDEC STD MS-012, VARIATION AC.

**Minimum Land Pattern - SO-16**



- NOTES:
1. THIS LAND PATTERN IS FOR REFERENCE PURPOSES ONLY. CONSULT YOUR MANUFACTURING GROUP TO ENSURE YOUR COMPANY'S MANUFACTURING GUIDELINES ARE MET.
  2. REFERENCE IPC-SM-782A, RLP NO. 304A.

**Contact Information**

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